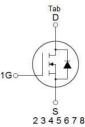


NCE Automotive N-Channel Super Trench II Power MOSFET

Description **General Features** The series of devices uses Super Trench II technology that is V_{DS} =100V,I_D =300A uniquely optimized to provide the most efficient high frequency $R_{DS(ON)}=1.7m\Omega$, typical@V_{GS}=10V switching performance. Both conduction and switching power • Excellent gate charge x R_{DS(on)} product(FOM) losses are minimized due to an extremely low combination of • Very low on-resistance R_{DS(on)} R_{DS(ON)} and Q_g. This device is ideal for high-frequency switching • 175 °C operating temperature and synchronous rectification. • Pb-free lead plating Application • 100% UIS tested • Automotive application 100% ∆Vds tested DC/DC Converter • AEC-Q101 gualified • Ideal for high-frequency switching and synchronous rectification **TOLL-8L**





Schematic Diagram

Package Marking and Ordering Information

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Device Marking	Device	Device Package	Reel Size	Tape width	Quantity		
AP023N10LL	NCEAP023N10LL	TOLL-8L	-	-	-		

Absolute Maximum Ratings (Tc=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	100	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	300	A
Drain Current-Continuous	I _D (T _C =100℃)	220	A
Pulsed Drain Current	I _{DM}	1200	A
Maximum Power Dissipation	PD	380	W
Derating factor		2.5	W/°C
Single pulse avalanche energy ^(Note 1)	E _{AS}	2800	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 175	°C
Thermal Characteristic	·		
Thermal Resistance, Junction-to-Case	Rejc	0.39	°C/W



Electrical Characteristics (Tc=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			·			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	100	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	Igss	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	±100	nA
On Characteristics	I					
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250µA	2.0	3.0	4.0	V
Drain-Source On-State Resistance	RDS(ON)	V_{GS} =10V, I_D =20A	-	1.7	2.3	mΩ
Gate resistance	Rg	F=1.0MHz	-	2.0	-	Ω
Forward Transconductance	G FS	V _{DS} =5V,I _D =150A	-	200	-	S
Dynamic Characteristics						1
Input Capacitance	Clss	V _{DS} =50V,V _{GS} =0V,	-	17500	-	pF
Output Capacitance	Coss		-	1100	-	pF
Reverse Transfer Capacitance	Crss	F=1.0MHz	-	50	-	pF
Switching Characteristics (Note 2)						
Turn-on Delay Time	t _{d(on)}		-	34	-	nS
Turn-on Rise Time	tr	V _{DD} =50V,I _D =20A	-	27	-	nS
Turn-Off Delay Time	t _{d(off)}	V _{GS} =10V,R _G =1.6Ω	-	78	-	nS
Turn-Off Fall Time	t _f		-	30	-	nS
Total Gate Charge	Qg	V _{DS} =50V,I _D =20A,	-	240	-	nC
Gate-Source Charge	Q _{gs}		-	75	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V		60	-	nC
Drain-Source Diode Characteristics			· ·		I	
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _S =20A	-	-	1.2	V
Diode Forward Current	Is		-	-	300	Α
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F = 20A	-	101	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs	-	280	-	nC

Notes:

1. EAS condition : Tj=25 $^\circ \!\! C$,VDD=50V,VG=10V,L=0.5mH,Rg=25 Ω

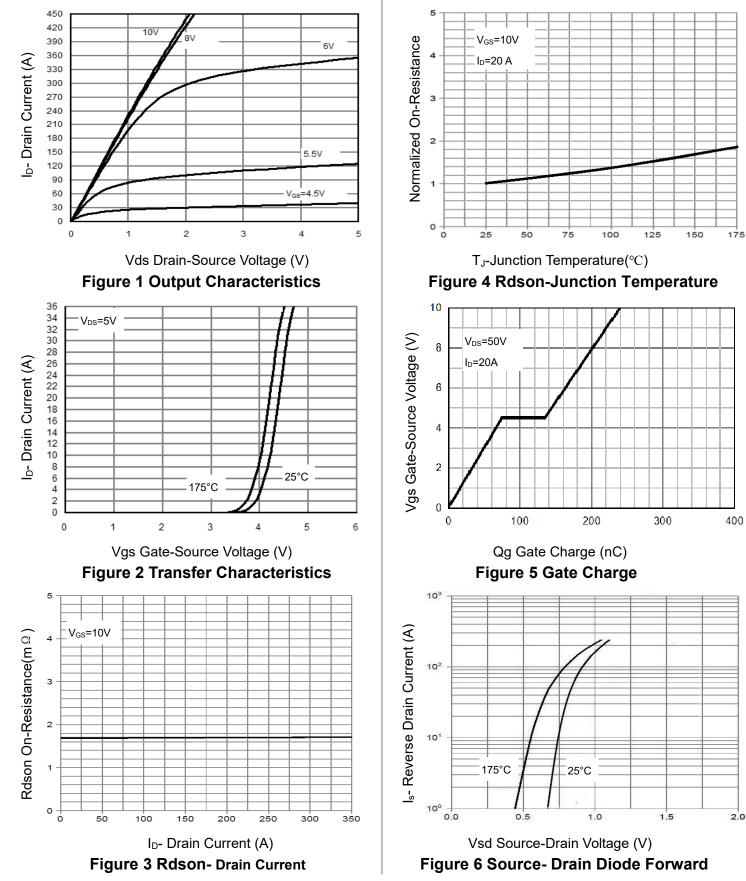
2. Guaranteed by design, not subject to production

3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsin k, assuming a maximum junction temperature of TJ(MAX)=175° C. The SOA curve provides a single pulse rating.



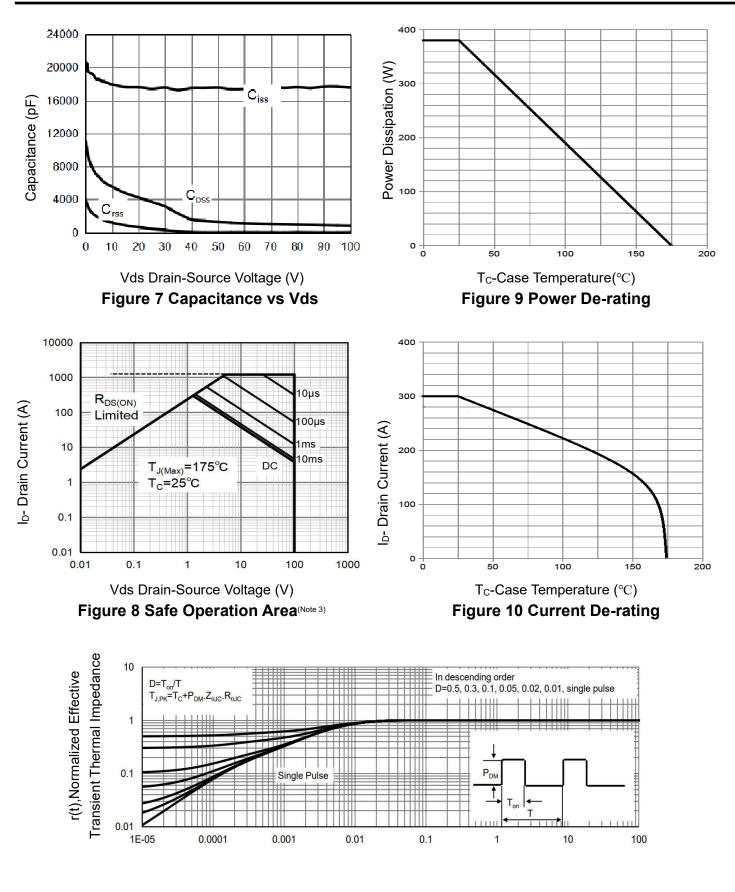
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Typical Electrical and Thermal Characteristics





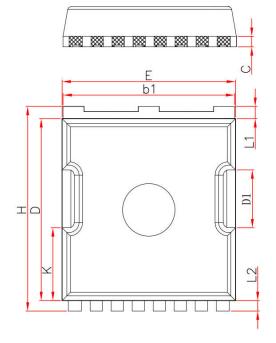
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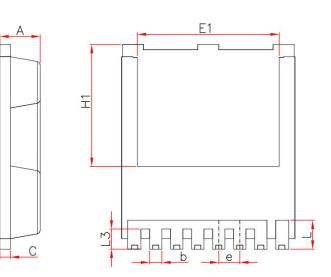


Square Wave Pluse Duration(sec) Figure 11 Normalized Maximum Transient Thermal Impedance



TOLL Package Information





Symbol	Millimeters			
	Min.	Nom.	Max.	
А	2.20	2.30	2.40	
b	0.65	0.75	0.85	
b1	9.70	9.80	9.90	
С	0.50	0.60	0.70	
D	10.30	10.40	10.50	
D1	3.15	3.3	3.45	
Е	9.70	9.90	10.10	
E1	8.00	8.10	8.20	
е	1.10	1.20	1.30	
Н	11.6	11.7	11.8	
H1	6.85	6.95	7.05	
K	4.08	4.18	4.28	
L	1.60	1.65	2.10	
L1	0.60	0.70	0.80	
L2	0.50	0.60	0.70	
L3	1.05	1.20	1.30	

NOTES:

1.FOLLOW JEDEC STANDARD MO-299B.

2.ALL DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSION.

3. Exposed Cu



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